NSN 5961-01-412-5299

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-412-5299 **Inclosure Material:** Glass **Overall Length:** Between 0.205 inches and 0.225 inches **End Application:** Apn232, r.F. Assembly **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, dc **Capacitance Rating In Picofarads:** 0.15 **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No Fiig: A110a0